## NSN 5961-00-933-7694

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-933-7694 **Inclosure Material:** Glass and metal **Overall Length:** 0.502 inches **Terminal Length:** 0.440 inches **Electrode Internally-electrically Connected To Case:** Anode **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.557 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 400.0 breakover voltage, dc **Current Rating Per Characteristic:** 250.00 amperes forward current, average absolute **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Terminal Type And Quantity:** 2 tab, solder lug and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0